

Midterm 1 test

Level: 1st Year

Material: Electronics Fundamental

Date: Thursday 10/04/2025

Duration: 2h

Exercise1: (5 points)

Assuming that the diodes in the circuit opposite are ideal, the input voltage is applied across points A and B, and the output voltage is measured across points C and D.

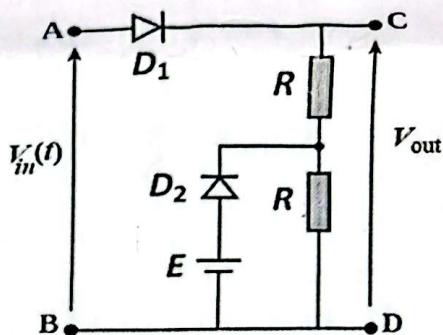
1. For each combination indicated in the table below, you are asked to:

- Provide the equivalent circuit diagram of the setup.
- Specify the condition(s) on the input voltage.
- Determine the expression of the output voltage.

2. Plot the transfer characteristic of the circuit.

3. Plot $V_{out}(t)$

We give: $V_{in}(t) = 15 \sin(\omega t)$, $E = 10V$, $R = 4 k\Omega$

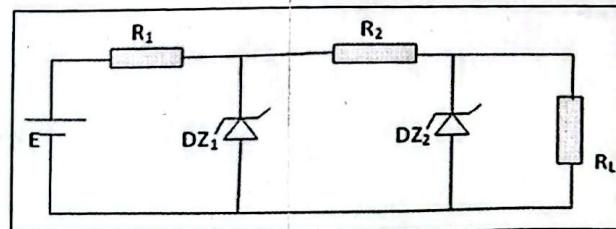


D1 State	D2 State	Condition on $V_{in}(t)$	$V_{out}(t)$
ON	ON		
ON	OFF		
OFF	ON		
OFF	OFF		

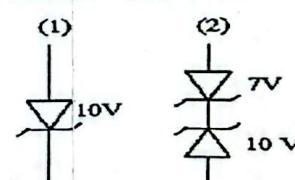
Exercise2: (5 points)

1. For the circuit shown in figure, calculate I_{Z_1} and I_{Z_2}

Given $E=35V$, $V_{Z_1} = 20V$, $V_{Z_2} = 10V$, $R_1 = 750\Omega$, $R_2 = 1k\Omega$ and $R_L = 2k\Omega$



2. One of the following elements (1 and 2) shown opposite, is alternately connected in place of the Zener diode DZ2. In each case, calculate the current I_L through R_L resistor



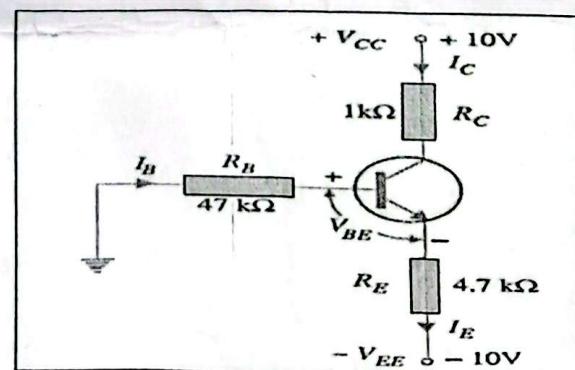
Exercise 3: (5 points)

1- Determine the Q point of the transistor circuit shown in the figure.

2- Determine the new Q-points when $V_{EE} = 5V$ and $15V$.

3- Draw the D.C. load line. Given $\beta = 100$ and $V_{BE} = 0.7V$.

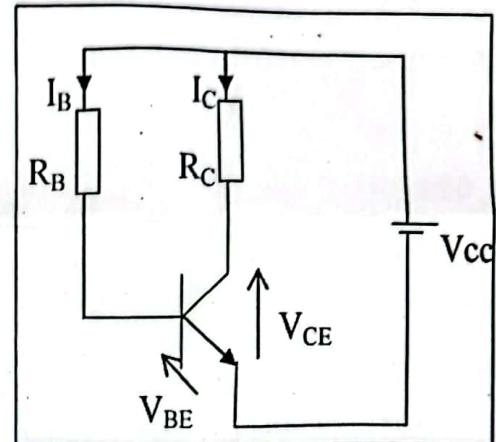
Assume $V_{CE(sat)} = 0V$.



Exercise 4: (5 points)

We consider the following circuit that includes a transistor with a static current gain $\beta=100$, the voltage between the base and emitter is $V_{BE} = 0.7 \text{ V}$, $R_C = 2 \text{ k}\Omega$ and $V_{CC} = 15 \text{ V}$.

1. We desire to have 5 mA through the resistor R_C , what value of resistance R_B should be chosen? Deduce V_{CE} .
2. If we vary R_B , then I_B varies, and thus I_C also varies. Taken a null value of V_{CE} at saturation, what is the maximum value that I_C can reach?.
3. What is the minimum value of I_B required to saturate the transistor?



Good Luck